

### DESCRIPTION

The BSS138L is available in SOT-23 package

# ORDERING INFORMATION

Package Type	Part Number				
SOT-23	BSS138L				
Note	SPQ: 3,000pcs/Reel				
AiT provides all RoHS Compliant Products					

## FEATURES

• 50V/0.2A

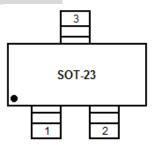
R<sub>DS(ON)</sub> = 3.5Ω (Max) @V<sub>GS</sub>=5V I<sub>D</sub>=0.2A R<sub>DS(ON)</sub> = 10Ω (Max) @V<sub>GS</sub>=2.75V I<sub>D</sub>=0.2A

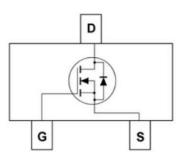
- Super High dense cell design for extremely low R<sub>DS(ON)</sub>
- Reliable and Rugged
- Low Threshold Voltage(0.5V-1.5V) Make it Ideal for Low Voltage Applications.
- Available in SOT-23 package

#### APPLICATION

 Power Management in DC/DC Converters Portable and Battery-powered Products.

#### **PIN DESCRIPTION**







# ABSOLUTE MAXIMUM RATINGS

V <sub>DS</sub> , Drain-Source Voltage	50V
V <sub>GS</sub> , Gate Source Voltage	±20V
I <sub>D</sub> , Drain Current-Continuous	0.2A

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

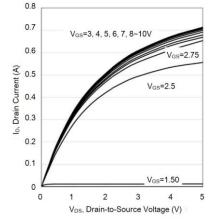
#### T<sub>A</sub>=25°C, unless otherwise noted

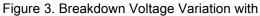
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit		
Off Characteristics								
Drain to Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250µA	50	-	-	V		
Zero-Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V	-	-	0.5	μA		
		$V_{DS}$ =25V, $V_{GS}$ =0V	-	-	0.1			
Gate Body Leakage Current, Forward	Igssf	$V_{GS}$ =20V, $V_{DS}$ =0V	-	-	100	nA		
Gate Body Leakage Current, Reverse	Igssr	$V_{GS}$ =-20V, $V_{DS}$ =0V	-	-	-100	nA		
On Characteristics								
Gate Threshold Voltage	$V_{\text{GS(th)}}$	V <sub>GS</sub> =V <sub>DS</sub> , I <sub>D</sub> =1.0mA 0.5		-	1.5	V		
Chatia Dasia Cauna On Dasiatana	R <sub>DS(ON)</sub>	V <sub>GS</sub> =5.0V, I <sub>D</sub> =0.2A	-	-	3.5			
Static Drain-Source On-Resistance		$V_{GS}$ =2.75V, I <sub>D</sub> =0.2A	-	-	10	Ω		
Drain-Source Diode Characteristics and Maximum Ratings								
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	V <sub>GS</sub> =0V, I <sub>S</sub> =0.2A	-	-	2.5	V		



## TYPICAL CHARACTERISTICS

Figure 1. Output Characteristics





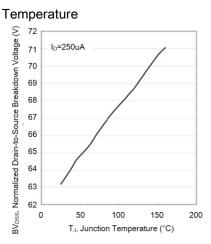


Figure 5. On-Resistance Variation with Temperature

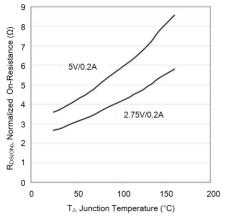


Figure 2. Transfer Characteristics

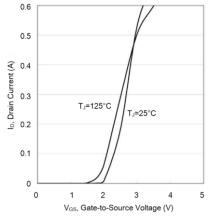


Figure 4. Gate Threshold Variation with Temperature

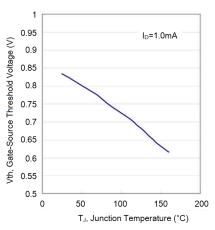


Figure 6. On-Resistance vs. Drain Current

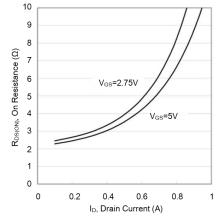






Figure 7. On-Resistance vs. Gate-to-Source Voltage

I<sub>D</sub>=0.2A

2

3 4 5 6

V<sub>GS</sub>, Gate-to-Source Voltage (V)

10

8

6

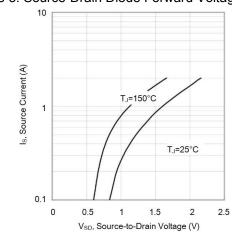
4

2

0

0 1

 $R_{DS(ON)},$  On Resistance ( $\Omega)$ 

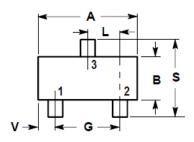


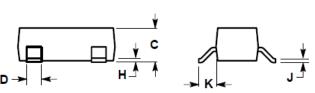
#### Figure 8. Source-Drain Diode Forward Voltage

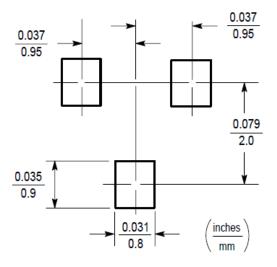


# PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)







DIM	MILLIN	IETERS	INCHES		
	MIN	MAX	MIN	MAX	
А	2.80	3.04	0.1102	0.1197	
В	1.20	1.40	0.0472	0.0551	
С	0.89	1.11	0.0350	0.0440	
D	0.37	0.50	0.0150	0.0200	
G	1.78	2.04	0.0701	0.0807	
Н	0.013	0.100	0.0005	0.0040	
J	0.085	0.177	0.0034	0.0070	
к	0.35	0.69	0.0140	0.0285	
L	0.89	1.02	0.0350	0.0401	
S	2.10	2.64	0.0830	0.1039	
V	0.45	0.60	0.0177	0.0236	



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